

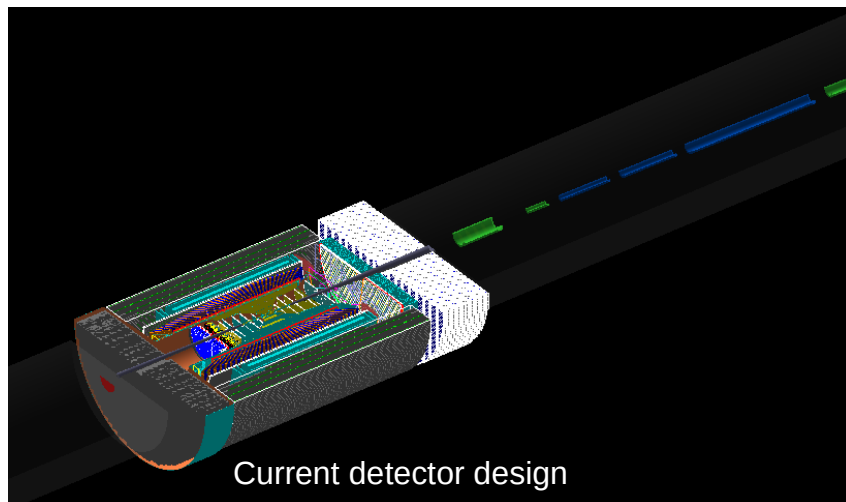
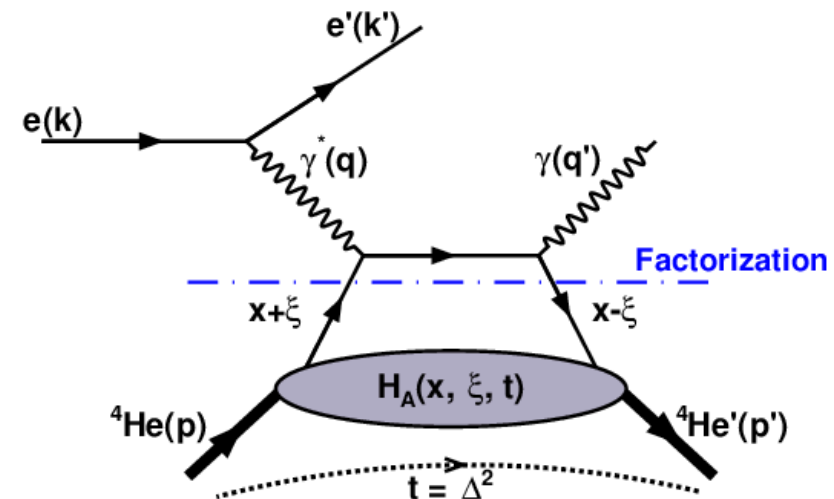
# Simulation and instrumentation for the Roman Pot in the future Electron-Ion Collider

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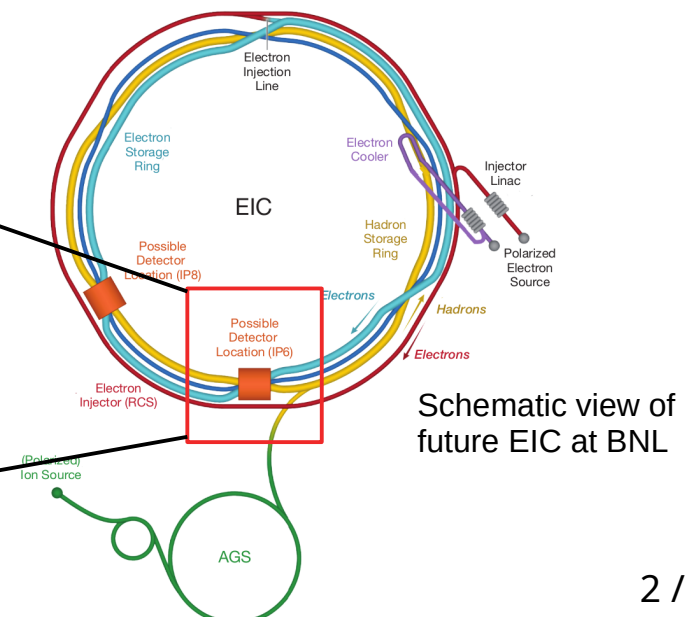
Carlos Munoz Camacho      supervisor

# Exclusive process in future EIC

- The Generalized Parton Distribution (GPD) framework is a recent approach to understand the nucleon structure in further detail. It can also be used to study the spin structure of the proton.
- Deep Virtual Compton Scattering (DVCS) is an exclusive process that can provide access to the GPDs of the proton  
 $e^- + p \rightarrow e^- + \gamma + p$
- A new electron ring will be added to Relativistic Heavy Ion Collider (RHIC) and the requirements:
  - highly polarized e- beam (~70%) and proton beam (~70%)
  - ion beam from deuteron to gold, lead or uranium
  - high luminosity:  $10^{33} \sim 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$
  - e+proton center of mass energy up to 140 GeV

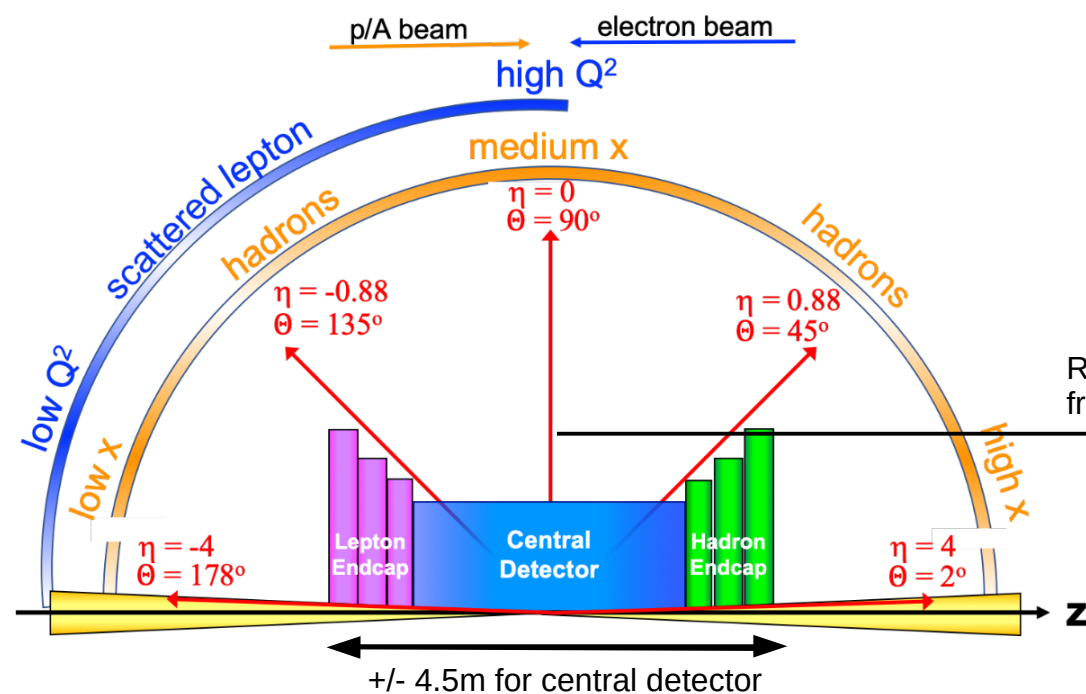


The first data taking will be in 2030

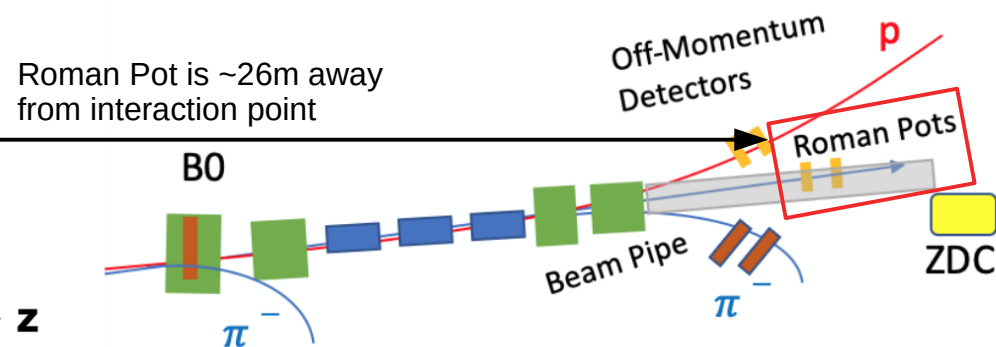


# Exclusive process in future EIC

- In the DVCS process,  $e^- + p \rightarrow e^- + \gamma + p$ 
  - most scattered  $e^-$  and photons go to the lepton Endcap and some toward the barrel detector.
  - The recoil protons go to the far-forward region and will be detected by the Roman Pots



## Far-forward region



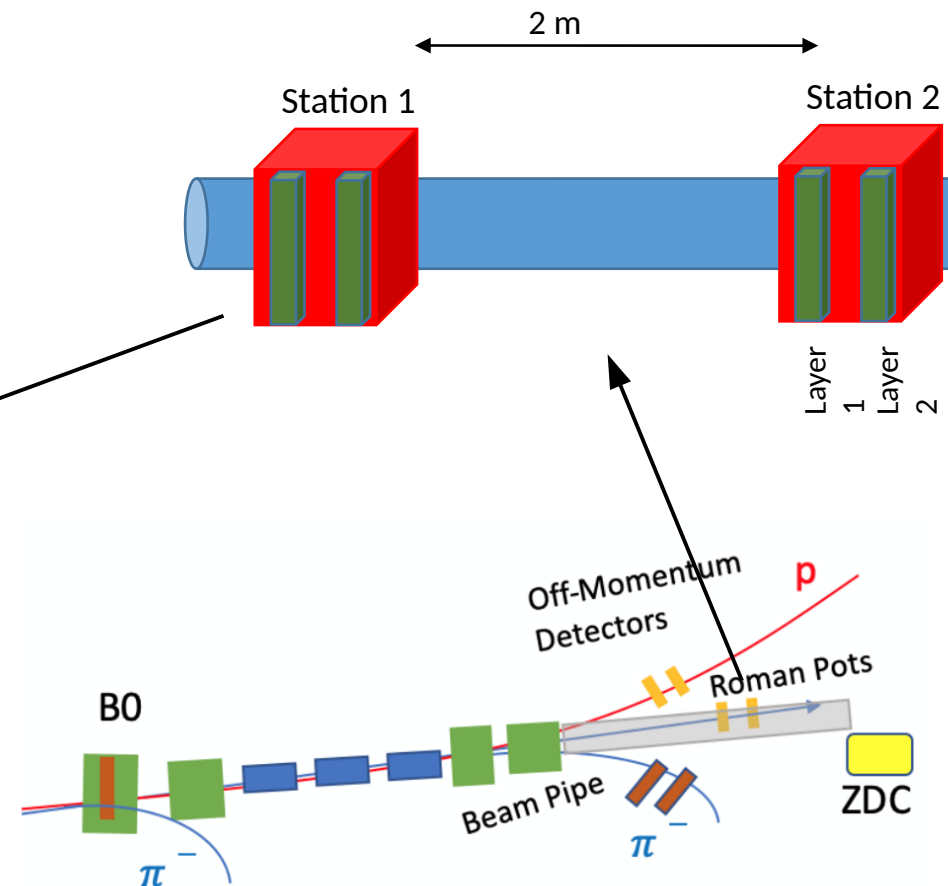
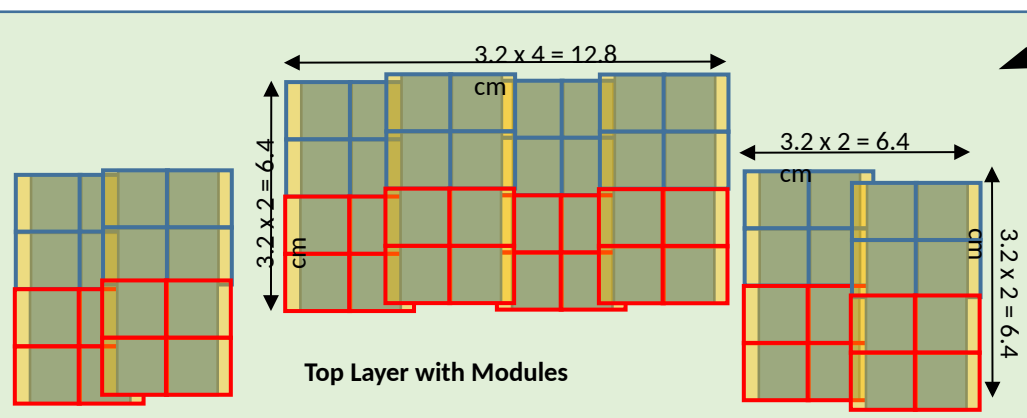
Green and blue boxes are dipole and quadrupole magnets

# Roman Pots in EIC

- 2 stations and 4 layers silicon detector to detect the recoiled DVCS proton/ion
- Use AC-LGAD to perform the precised 4D measurements and high speed readout
- Use 1TDC(Time Digital Converter) + 1ADC(Analog Digital Converter)
- Around 0.5 million channels in total are required

station	(0.85, 26) (0.94, 28)
dimension	(25cm, 10cm, n/a)
theta	$0. < \theta < 5.5$ mrad

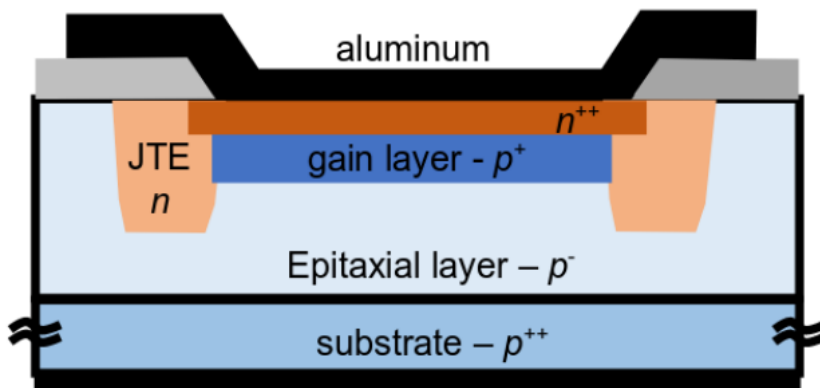
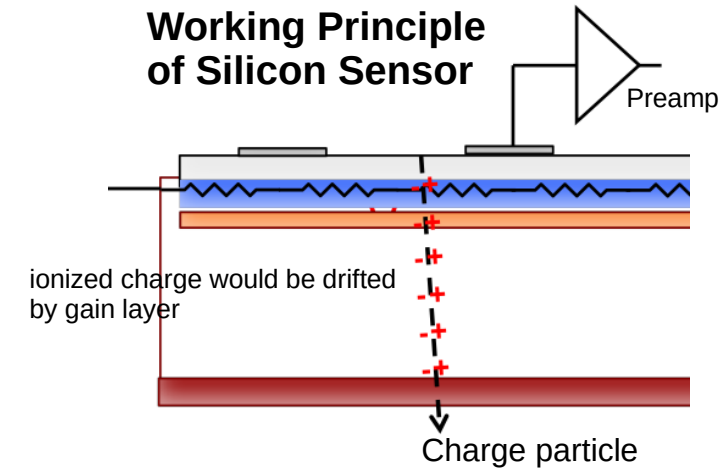
position resolution requirement	timing resolution requirement	N channels per ASIC	Sensor size	power consumption (W/cm <sup>2</sup> )
100 $\mu$ m	30-40ns	1024	500 $\mu$ m	1.07



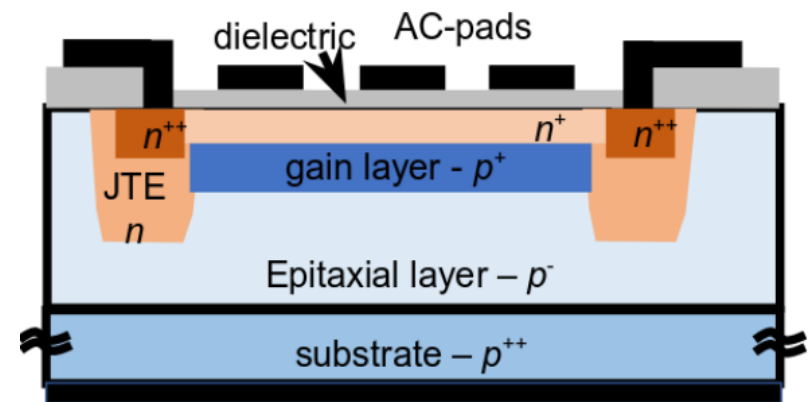
# AC Low Gain Avalanche Diode

- AC-LGAD is adapted from LGAD, which is used in HGTD in ATLAS
- AC-LGAD features:
  - AC couple signal
  - 100% fill factor(no dead region)
  - fast timing information as LGAD
  - signal sharing between nearby pads to improve position resolution (Barycenter)

} -> 4D measurements



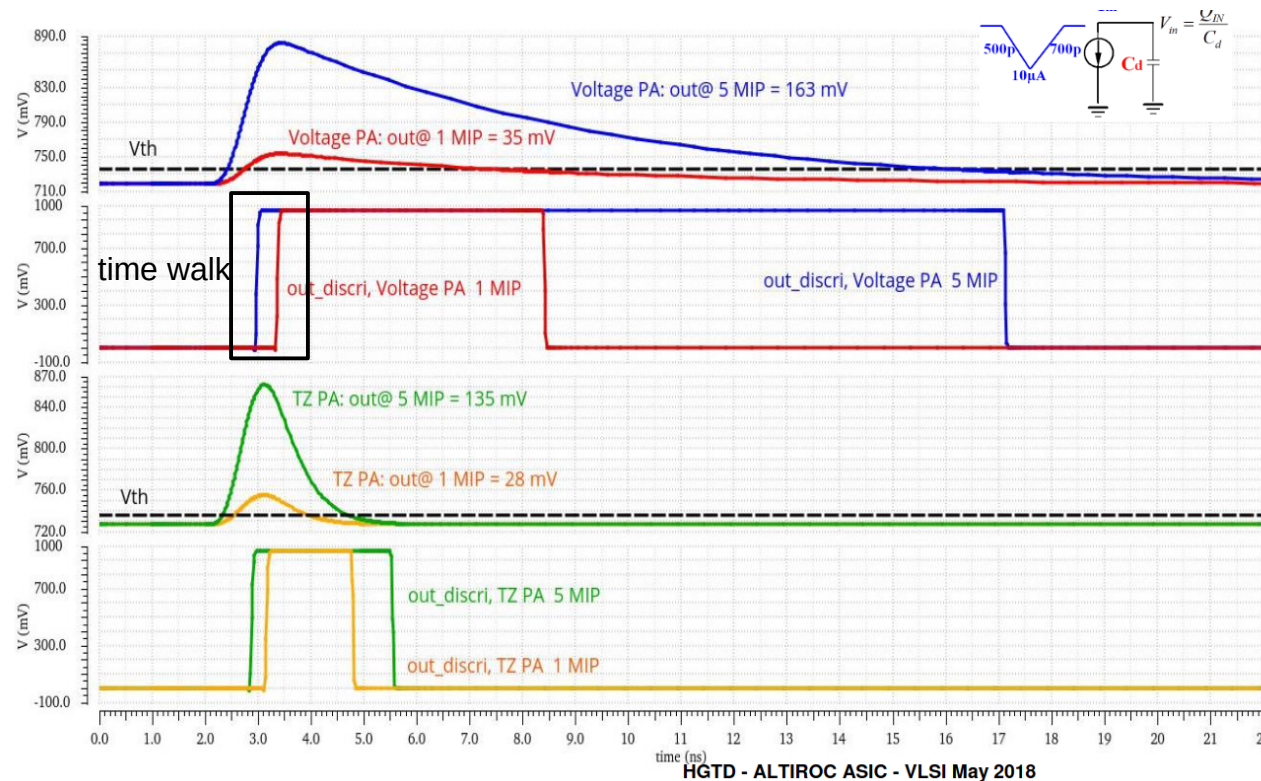
The schematic DC-LGAD



The schematic AC-LGAD

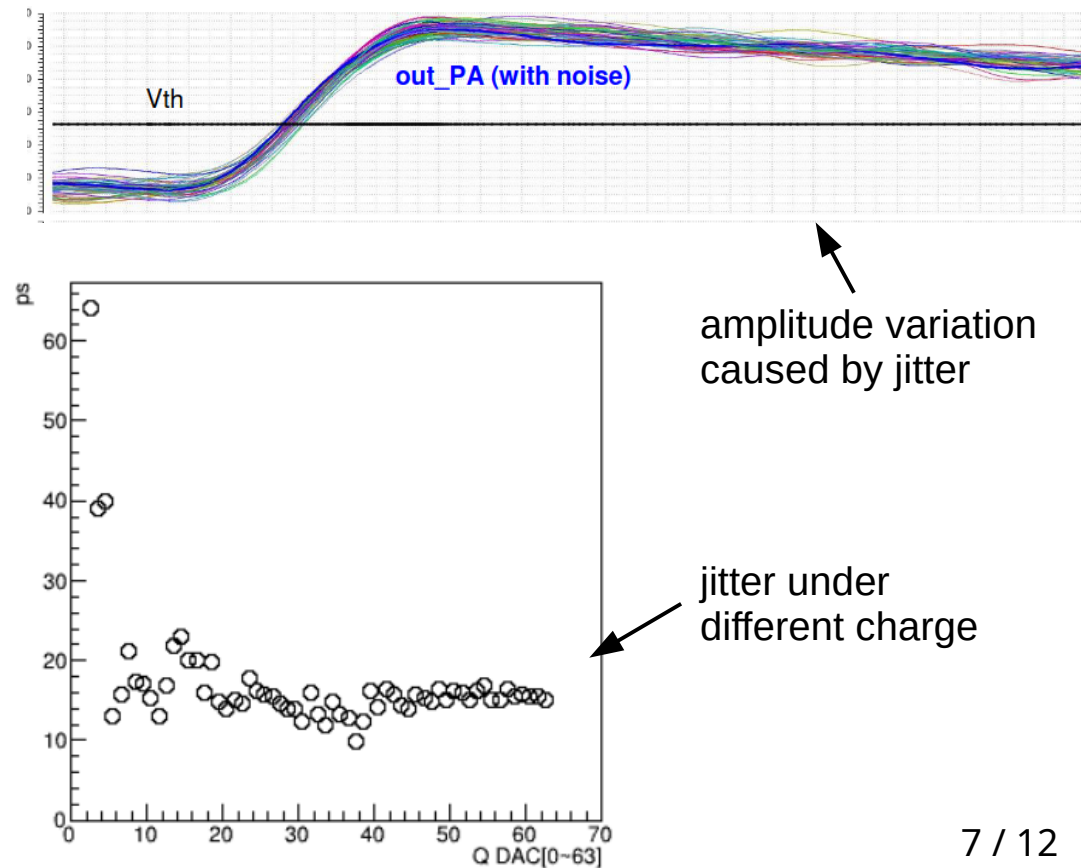
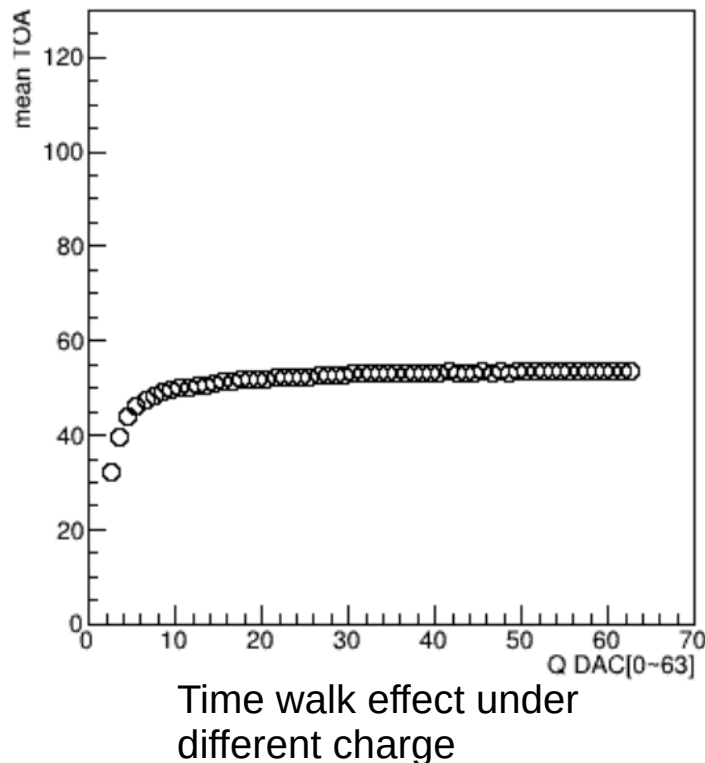
# Readout chip of AC-LGAD

- Now, we use well developed **ALTIROC** to study the property of AC-LGAD , which use **2 TDCs** to measure signal
  - TOA (Time of Arrival)
  - TOT (Time over threshold)
- 2 different types of pre-amplifiers are implemented in the ASIC:
  - TZ (Transimpedance preamp), better in TOT measurements
  - VPA (Voltage preamp)
- Future **EICROC** will use **1TDC+1ADC**, since ADC can perform more precise charge measurements
- The first version of **EICROC** would be available in Sept.



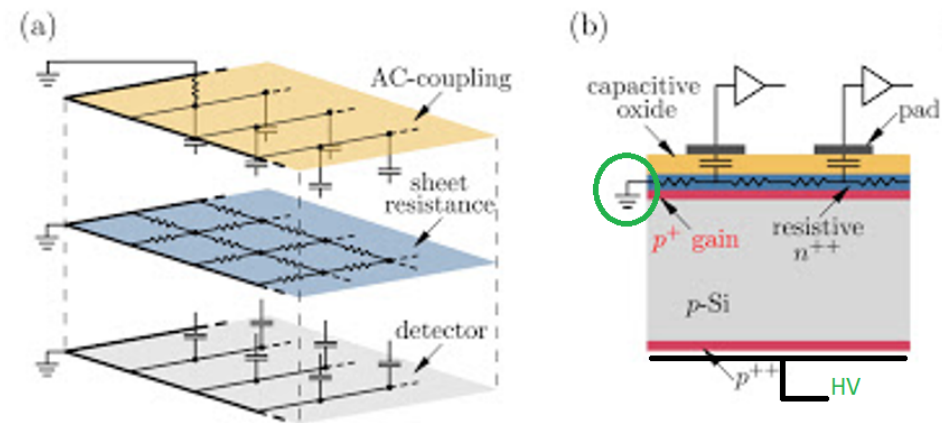
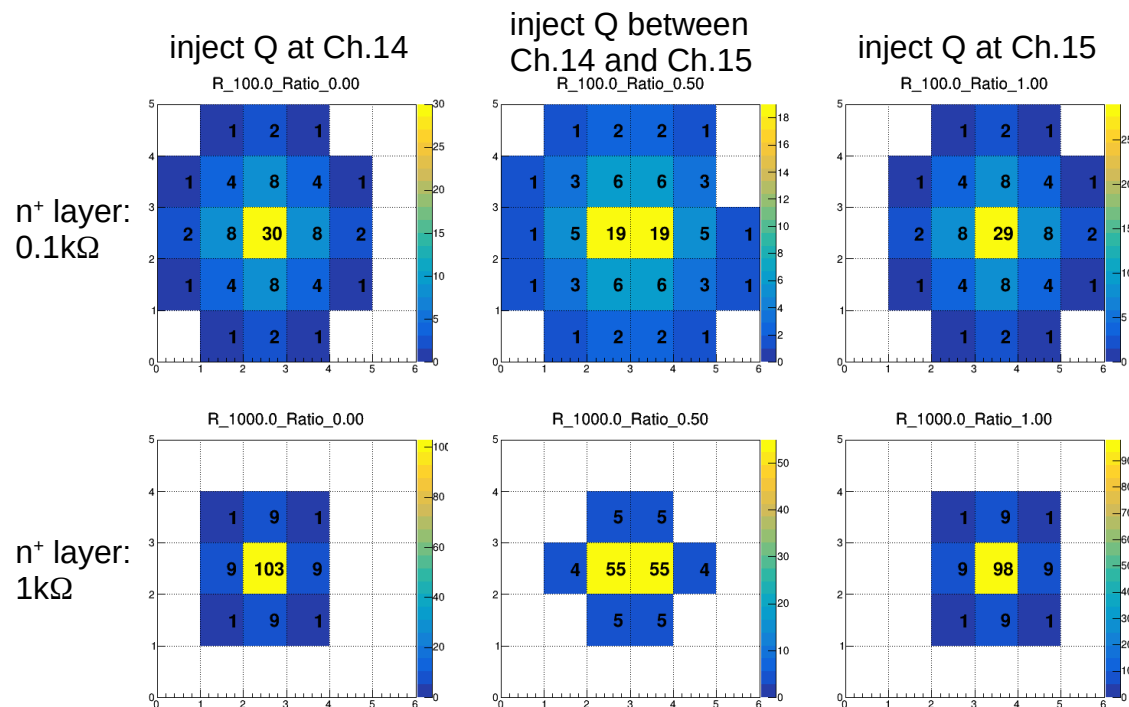
# TDC performance study

- time resolution electronic: TDC resolution + jitter + time walk
- Jitter: the noise is summed to the signal, causing amplitude variations
- Time walk: under given threshold, different scale of signal would have different time of arrival



# AC-LGAD simulation study

- The purpose is to know the optimal ADC resolution(8, 10, 12 bit) for the AC-LGAD readout
- Simulate different resistivity value of n<sup>+</sup> layer, from 0.1k - 10k  $\Omega$
- Simulate different inject charge -> saturation happen as limited dynamic range
- Simulate different inject position between two given channels, then using barycenter to reconstruct the inject position and calculate the position resolution.



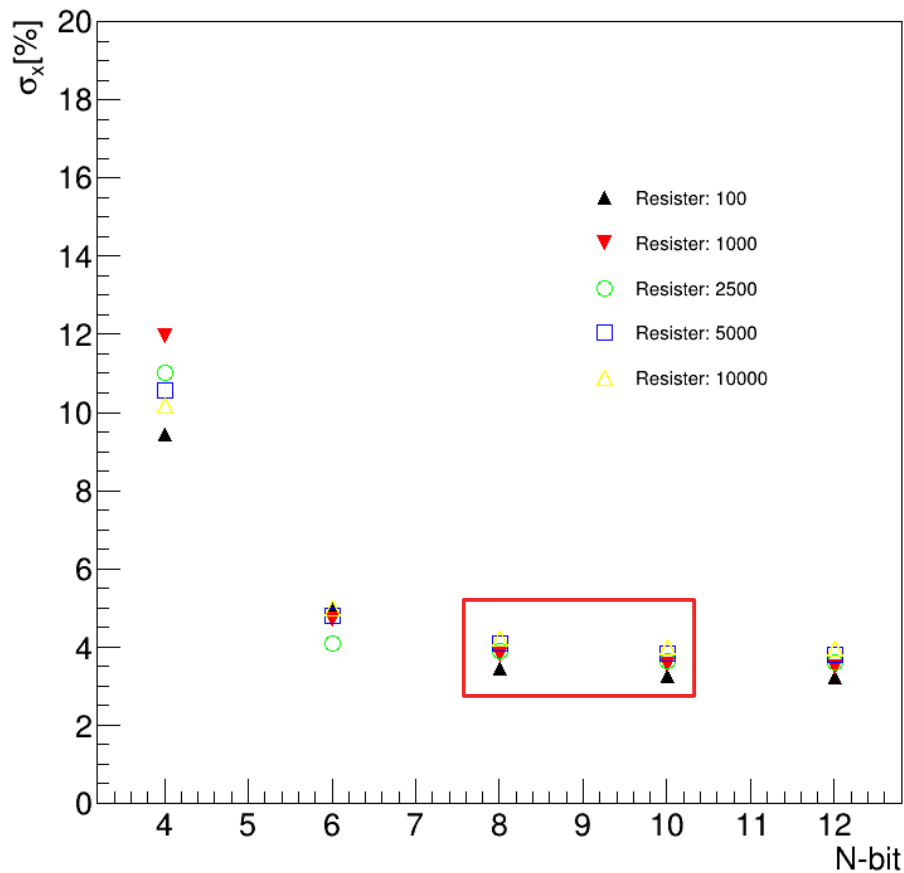
Simulation model of AC-LGAD sensor from our OMEGA



# Simulation of signal sharing among neighboring pixels

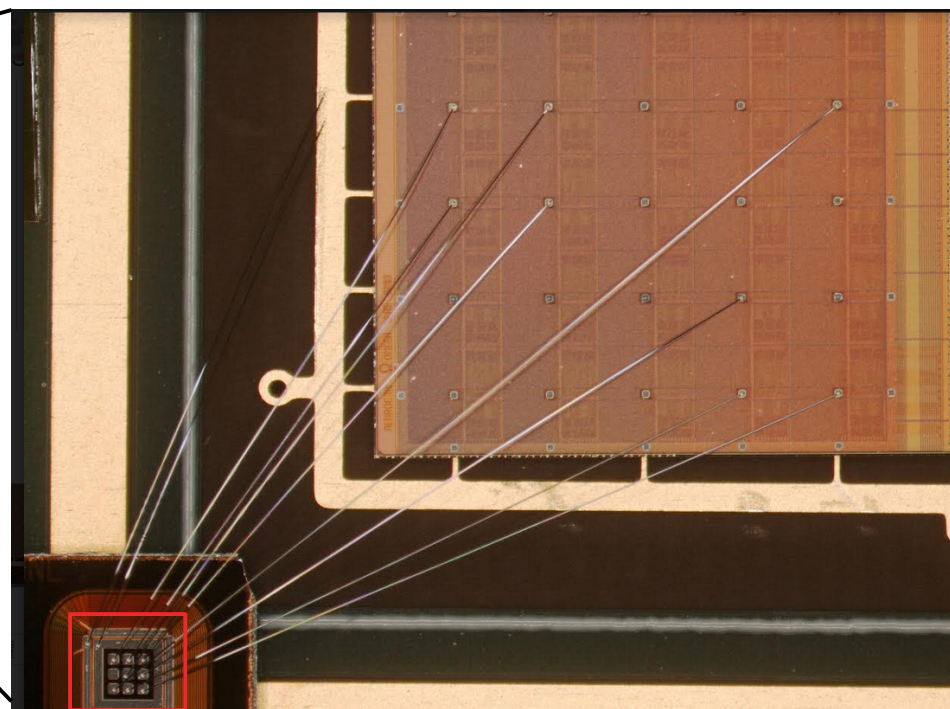
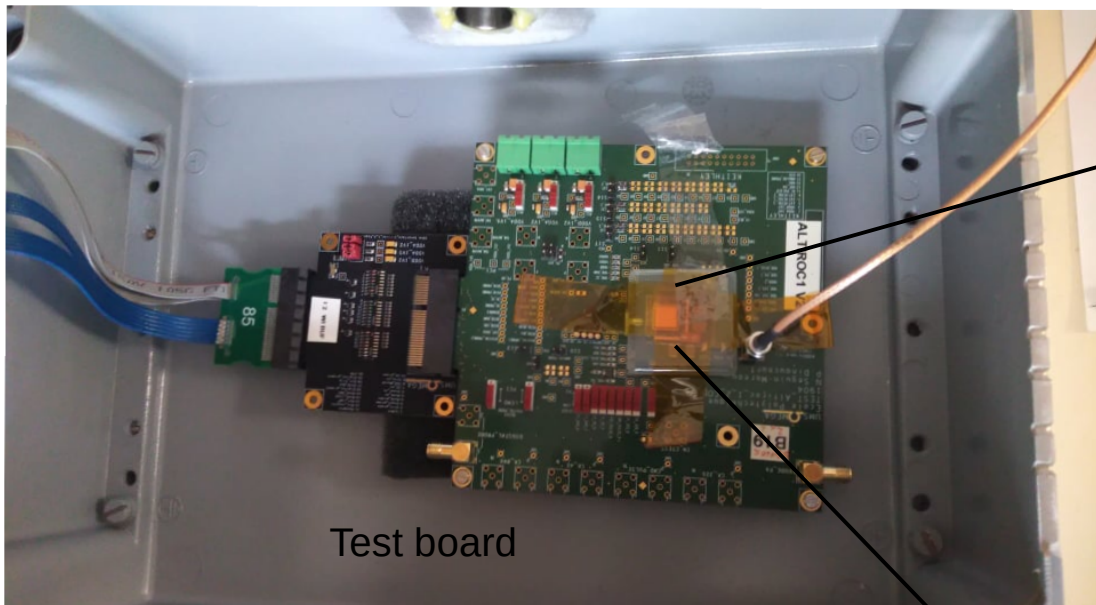
- Smear the charge deposition with landau distribution
- Implement the ADC algorithm, noise, threshold...etc
- We can reconstruct the injected position within 4% of the pixel size

Pos Reso  $\sigma_x$  @ N-bit and different Resister



No significant  $\sigma_x$  difference between ADC-8 & 10 bit  
And Due to the low power consumption and small size, **ADC-8bit is chosen**

# Sharing determination of AC-LGAD by charge injection



22.4%	← <b>Ch.02</b> →	23.1%
	↓	
	13.0%	

inject 8pF @ ch.02

1	2	7
NC	6	18
21	19	24

Sharing of charge injection

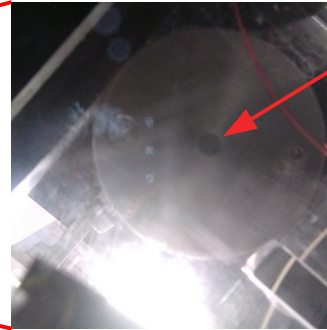
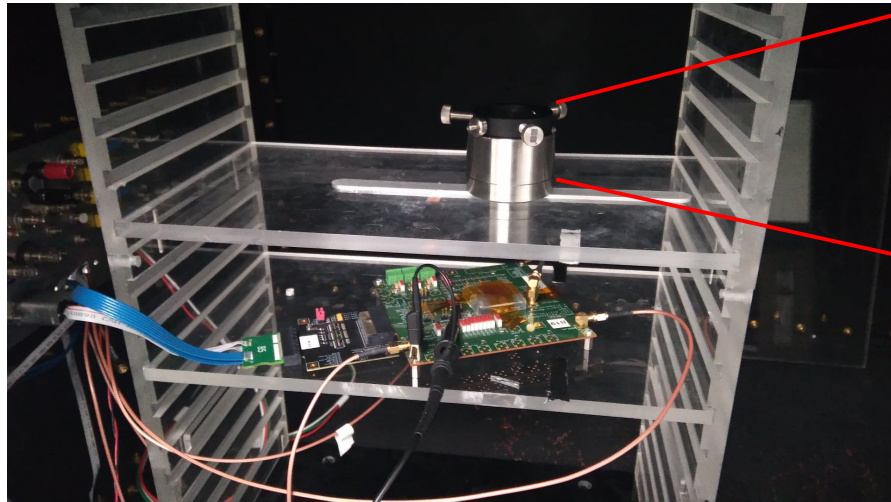
AC-LGAD wire bond to ASIC

Quantify the sharing by charge injection

		18.9%
10.0%	← <b>Ch.24</b> →	

inject 8pF @ ch.24

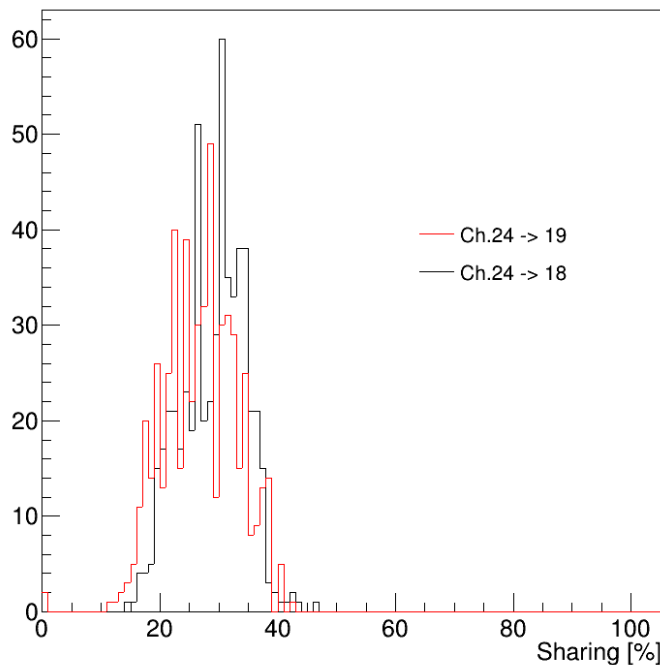
# Sharing determination of AC-LGAD by beta source



Beam hole for Sr-90 [37MBq]

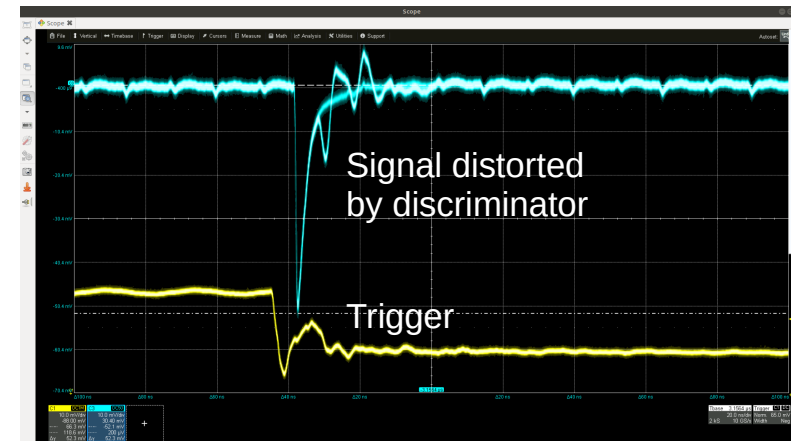
- The Beta source is placed right above sensor, 5~10 cm away.
- High voltage is -170V
- The whole setup put in black box

Sharing from Ch.24 to 18, 19



1	2	7
NC	6	13
21	19	24

24 share to 18 and 19  
 $TOT_{24} > TOT_{18}$  and  $TOT_{24} > TOT_{19}$



- From the beta source measurement, we can get ~30% of sharing
- The discrepancy in inject charge and beta source measurements comes from the TDC distortion

# Summary

- EICROC design and the test are in the progress
- The ADC-8bit will be adapted based on the chip position resolution study
- The sharing of AC-LGAD is determined by both charge injection(~15%) and beta source(~30%).

## Outlook:

- Using laser to quantify the sharing of AC-LGAD sensors. Laser can offer desired charge injection and position